

**ZXTD2090DE6**
**50V DUAL NPN LOW SATURATION SWITCHING TRANSISTOR IN SOT26**
**Features**

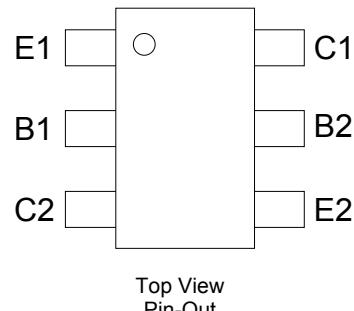
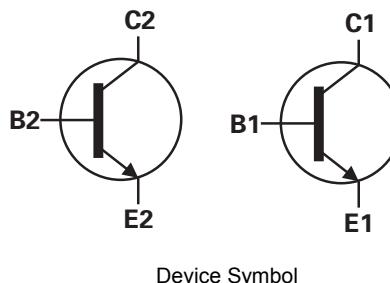
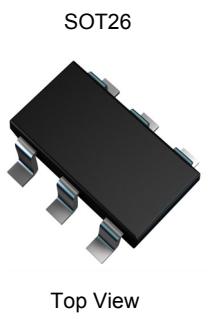
- $BV_{CEO} > 50V$
- $I_C = 1A$  High Continuous Current
- High Gain
- $R_{SAT} = 160m\Omega$  for Low Equivalent On Resistance
- Low Saturation Voltage  $V_{CE(SAT)} < -270mV$  @ 1A
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

**Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.015 grams (approximate)

**Applications**

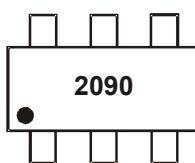
- LCD Backlighting Inverter Circuits
- Boost Functions in DC-DC Converters


**Ordering Information (Notes 4)**

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTD2090DE6TA	2090	7	8	3,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


2090 = Product Type Marking Code

ZXTD2090DE6

**Maximum Ratings – Q1 & Q2 Common** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	V
Collector-Emitter Voltage	$V_{CEO}$	50	V
Emitter-Base Voltage	$V_{EBO}$	7	V
Continuous Collector Current	$I_C$	1	A
Peak Pulse Current	$I_{CM}$	2	A
Base current	$I_B$	200	mA

**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

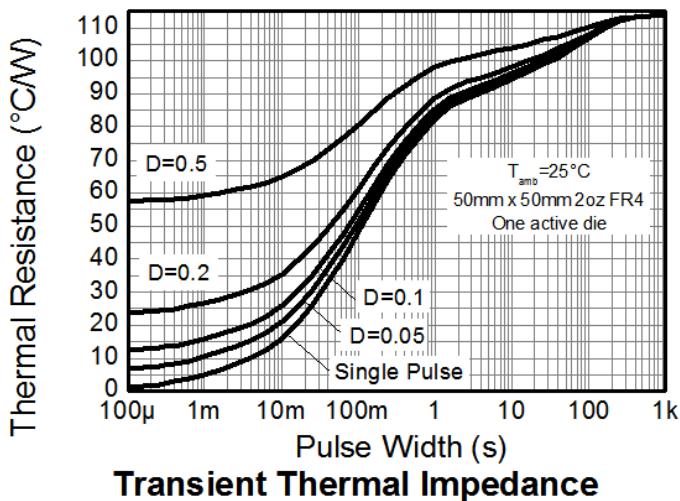
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	$P_D$	0.7	W mW/°C
		5.6	
		0.9	
		7.2	
		1.1	
		8.8	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	1.1	°C/W
		8.8	
		1.7	
		13.6	
		179	
Thermal Resistance, Junction to Lead	$R_{\theta JL}$	139	
		113	
		113	
		73	
		95.50	
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	°C

Notes:

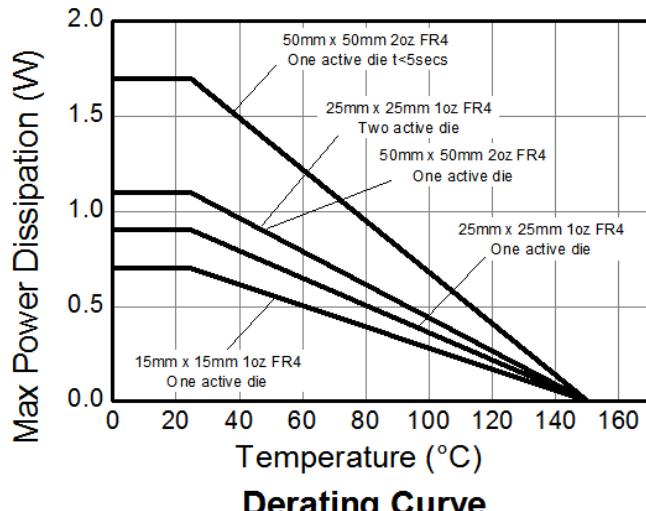
- 5. For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
- 6. Same as note (6), except the device is surface mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (6), except the device is surface mounted on 50mm x 50mm 2oz copper.
- 8. Same as note (8), except the device is measured at  $t < 5$  seconds.
- 9. For device with one active die, both collectors attached to a common heatsink.
- 10. For device with two active dice running at equal power, split heatsink 50% to each collector.
- 11. Thermal resistance from junction to solder-point (at the end of the collector lead).

**ZXTD2090DE6**

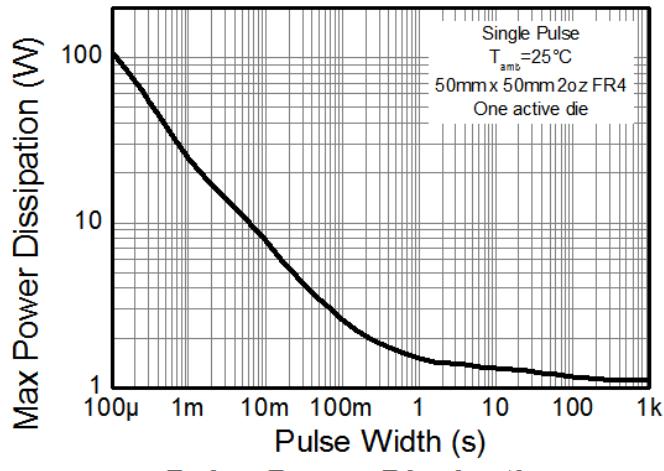
## Thermal Characteristics and Derating Information



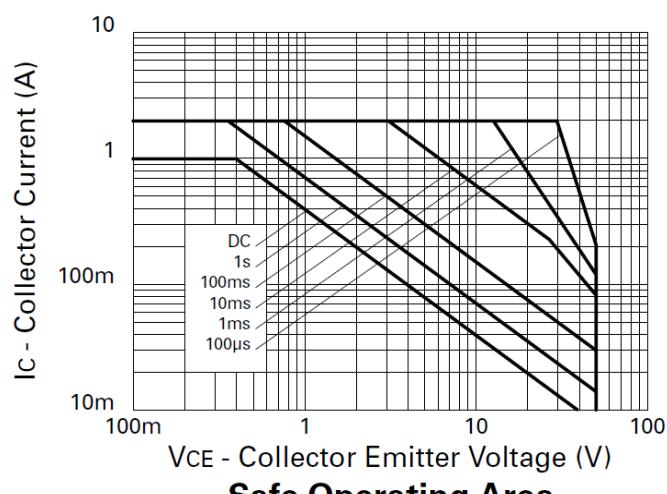
**Transient Thermal Impedance**



**Derating Curve**



**Pulse Power Dissipation**



**Safe Operating Area**

ZXTD2090DE6

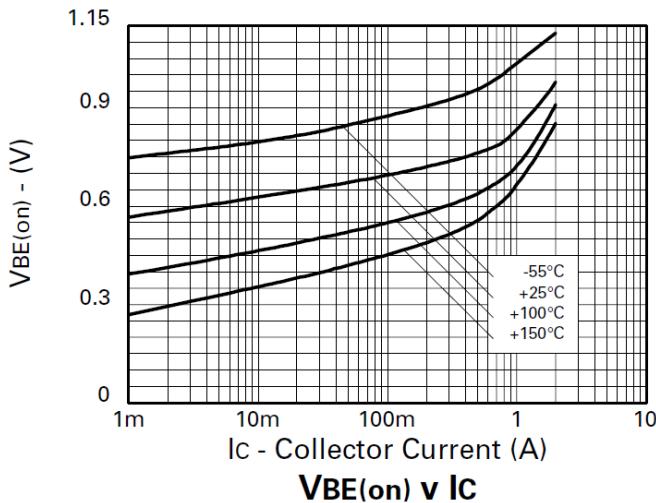
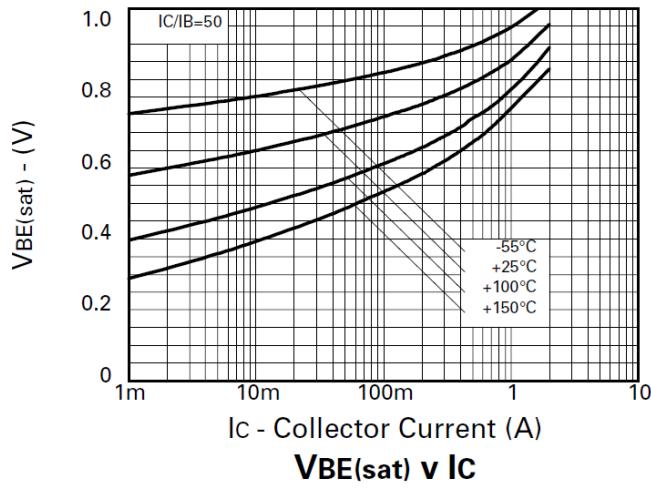
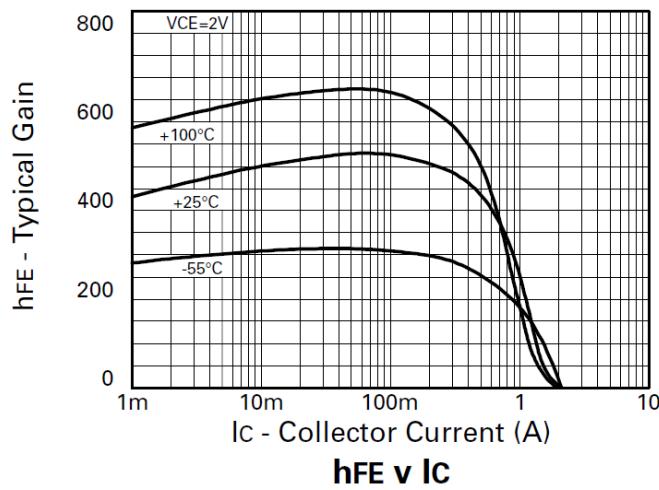
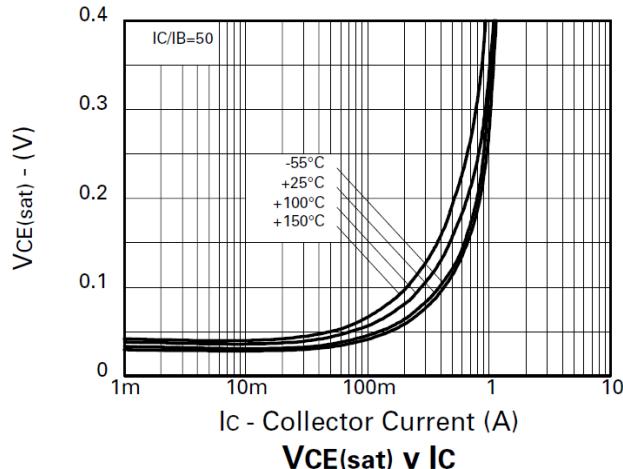
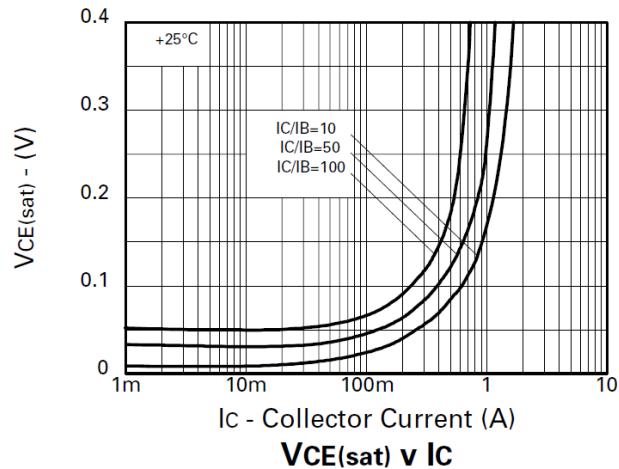
**Electrical Characteristics - Q1 & Q2 common** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	50			V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 12)	$BV_{CEO}$	50			V	$I_C = 10\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7			V	$I_E = 100\mu\text{A}$
Collector-Base Cutoff Current	$I_{CBO}$			10	nA	$V_{CB} = 40\text{V}$
Collector-Emitter Cutoff Current	$I_{CES}$			10	nA	$V_{CES} = 40\text{V}$
Emitter Cutoff Current	$I_{EBO}$			10	nA	$V_{EB} = 5.6\text{V}$
DC Current Gain (Note 12)	$h_{FE}$	200 300 200 75 20	420 450 350 130 60			$I_C = 10\text{mA}, V_{CE} = 2\text{V}$ $I_C = 100\text{mA}, V_{CE} = 2\text{V}$ $I_C = 500\text{mA}, V_{CE} = 2\text{V}$ $I_C = 1\text{A}, V_{CE} = 2\text{V}$ $I_C = 1.5\text{A}, V_{CE} = 2\text{V}$
Collector-Emitter Saturation Voltage (Note 12)	$V_{CE(\text{sat})}$		24 60 120 160	35 80 200 270	mV	$I_C = 100\text{mA}, I_B = 10\text{mA}$ $I_C = 250\text{mA}, I_B = 10\text{mA}$ $I_C = 500\text{mA}, I_B = 10\text{mA}$ $I_C = 1\text{A}, I_B = 50\text{mA}$
Base-Emitter Saturation Voltage (Note 12)	$V_{BE(\text{sat})}$		940	1100	mV	$I_C = 1\text{A}, I_B = 50\text{mA}$
Base-Emitter Turn-On Voltage (Note 12)	$V_{BE(\text{on})}$		850	1100	mV	$I_C = 1\text{A}, V_{CE} = 2\text{V}$
Output Capacitance	$C_{obo}$		10		pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$
Current Gain-Bandwidth Product	$f_T$		215		MHz	$V_{CE} = 10\text{V}, I_C = 50\text{mA}$ $f = 100\text{MHz}$
Turn-On Time	$t_{on}$		150		ns	$V_{CC} = 10\text{V}, I_C = 1\text{A}$
Turn-Off Time	$t_{off}$		425		ns	$I_{B1} = I_{B2} = 100\text{mA}$

Note: 12. Measured under pulsed conditions. Pulse width  $\leq 300\ \mu\text{s}$ . Duty cycle  $\leq 2\%$

**ZXTD2090DE6**

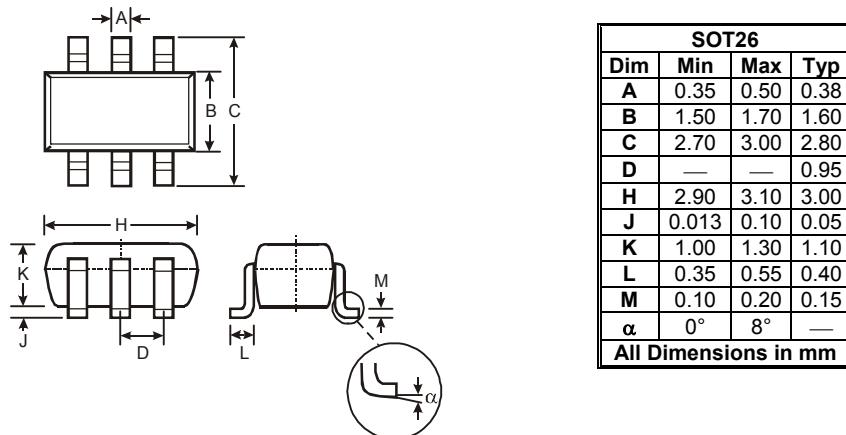
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**ZXTD2090DE6**

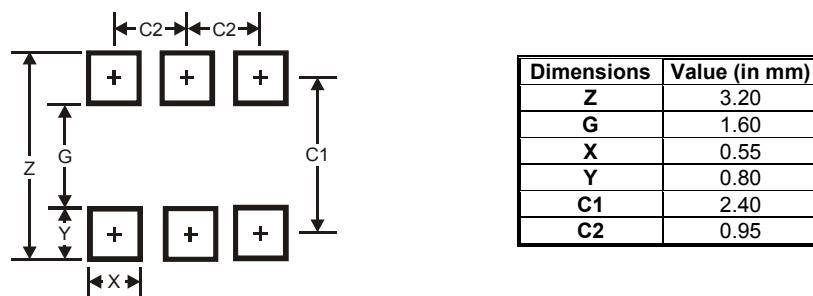
## Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2014, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)